

International
IOR Rectifier

32CTQ030SPbF
32CTQ030-1PbF

SCHOTTKY RECTIFIER

32 Amp

$$I_{F(AV)} = 30\text{Amp}$$

$$V_R = 30\text{V}$$

Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	30	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5\mu\text{s}$ sine	900	A
V_F @ 15Apk , $T_J = 125^\circ\text{C}$	0.40	V
T_J range	-55 to 150	$^\circ\text{C}$

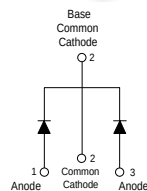
Description/ Features

The 32CTQ030.. Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

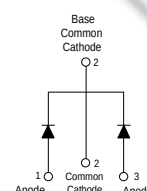
Case Styles

32CTQ030SPbF



D²PAK

32CTQ030-1PbF



TO-262

Voltage Ratings

Part number	32CTQ030SPbF, 32CTQ030-1PbF
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	32CTQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	30	A	50% duty cycle @ $T_C = 115^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	900	A	5 μs Sine or 3 μs Rect. pulse
	250		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	13	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1.20\text{ Amps}$, $L = 11.10\text{ mH}$
I_{AR} Repetitive Avalanche Current	3	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	32CTQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.49	V	@ 15A
	0.58	V	@ 30A
	0.40	V	@ 15A
	0.53	V	@ 30A
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	1.75	mA	$T_J = 25^\circ\text{C}$
	97	mA	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	0.233	V	$T_J = T_J \text{ max.}$
r_t Forward Slope Resistance	9.09	m Ω	
C_T Max. Junction Capacitance Per Leg	1300	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance Per Leg	8.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters		32CTQ	Units	Conditions
T _J	Max. Junction Temperature Range	-55 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-55 to 150	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case Per Leg	3.25	°C/W	DC operation * See Fig. 4
R _{thCS}	Typical Thermal Resistance, Case to Heatsink	0.50	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight	2 (0.07)	g (oz.)	
T	Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
		Max.	12 (10)	
Marking Device		32CTQ030S		Case style D ² Pak
		32CTQ030-1		Case style TO-262

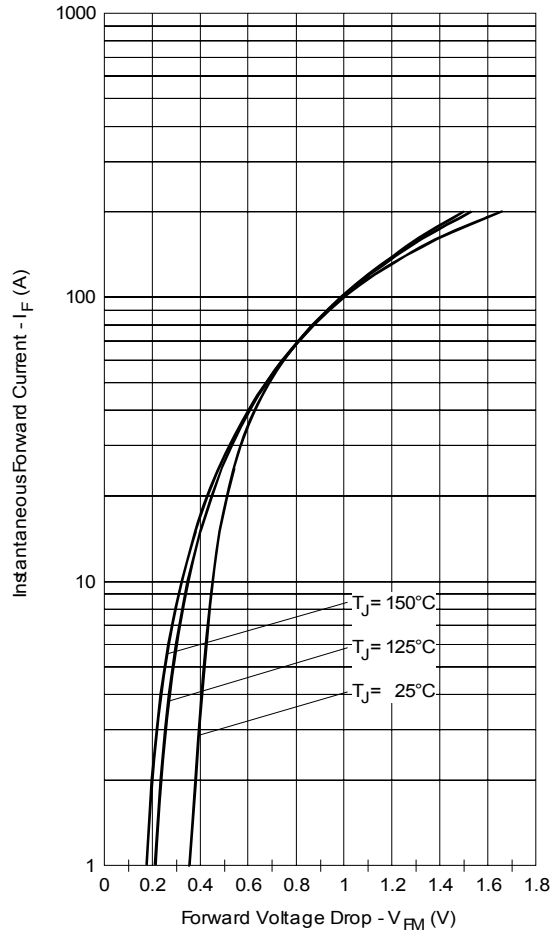


Fig. 1 - Maximum Forward Voltage Drop Characteristics

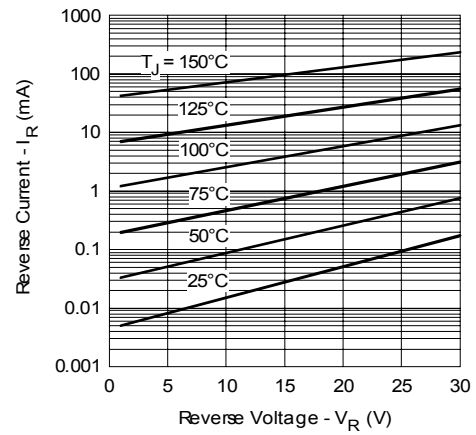


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

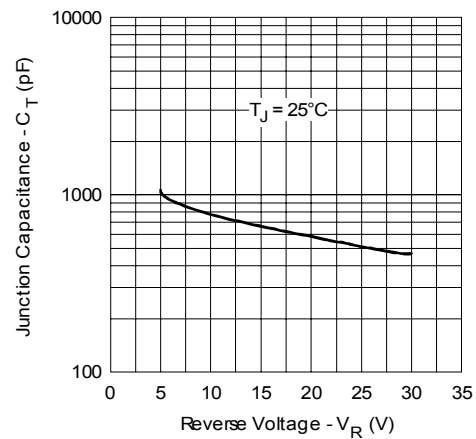


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

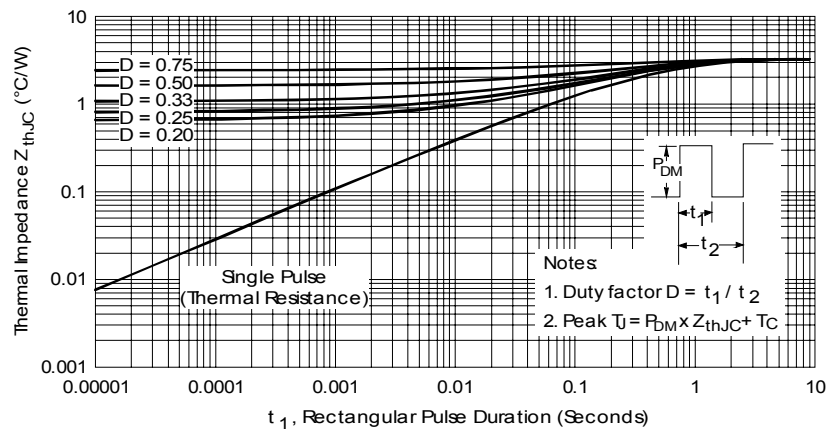


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

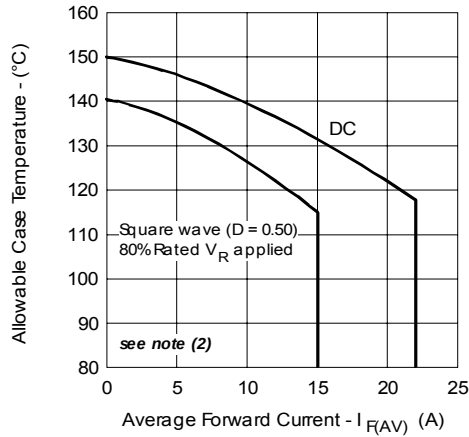


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

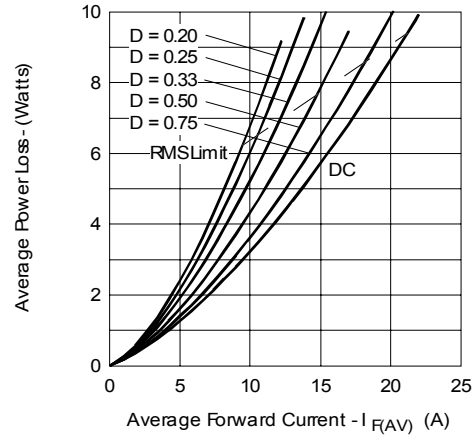


Fig. 6 - Forward Power Loss Characteristics

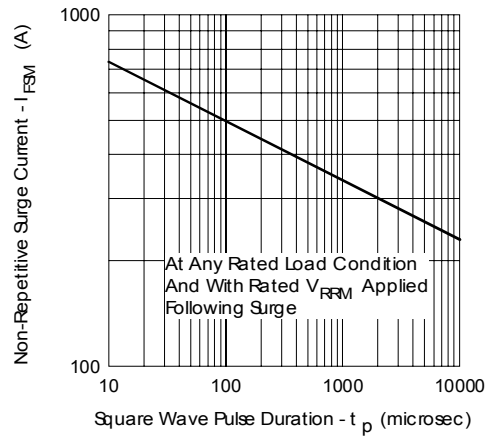


Fig. 7 - Maximum Non-Repetitive Surge Current

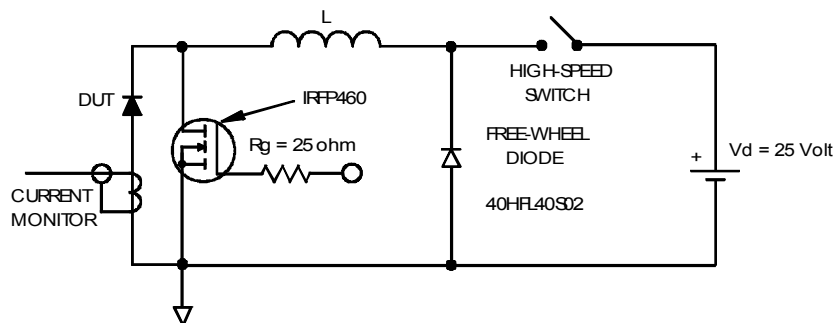


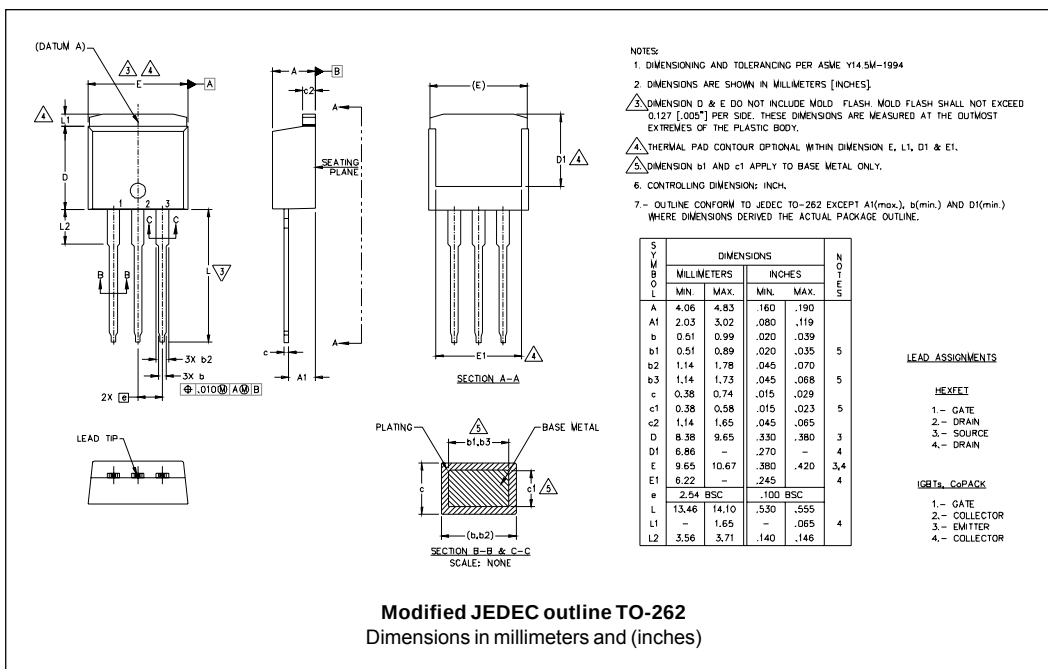
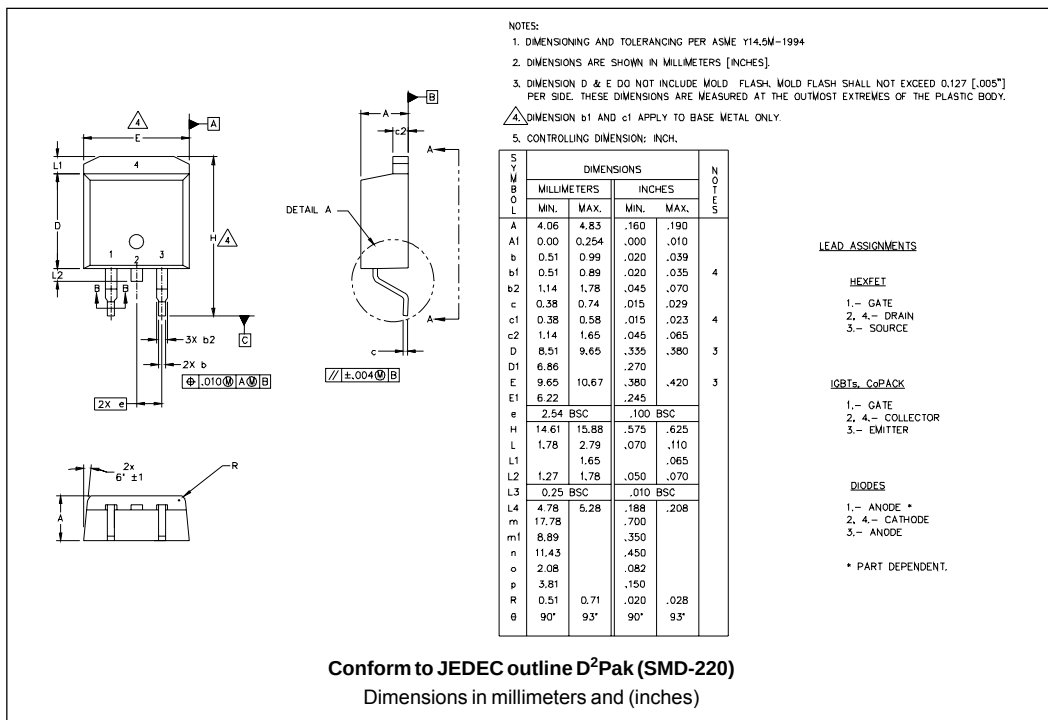
Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_{R1} (1 - D)$; $I_{R1} @ V_{R1} = 80\% \text{ rated } V_R$

Outlines Table

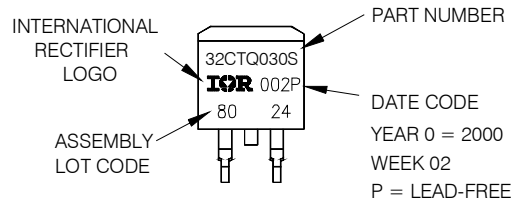


Part Marking Information

D²PAK

EXAMPLE: THIS IS A 32CTQ030S
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

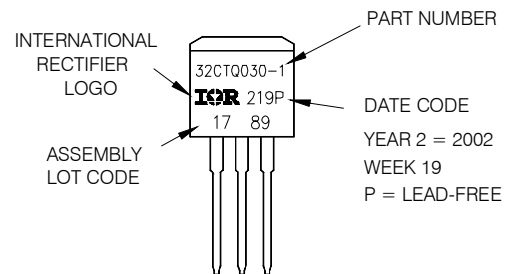
Note: "P" in assembly line position indicates "Lead-Free"



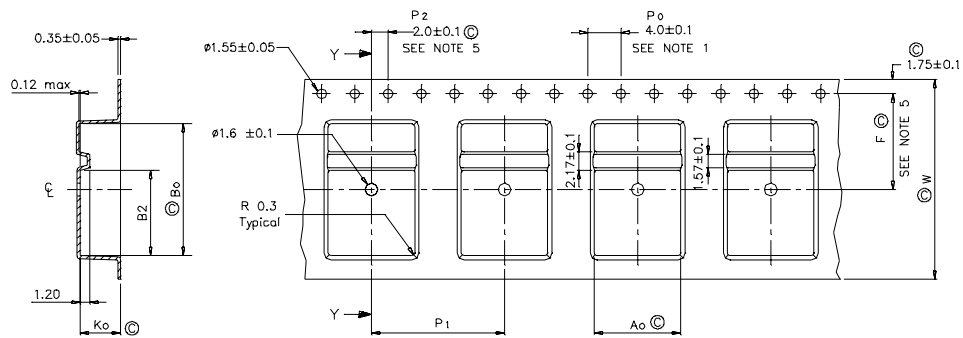
TO-262

EXAMPLE: THIS IS A 32CTQ030-1
LOT CODE 1789
ASSEMBLED ON WW 19, 2002

Note: "P" in assembly line position indicates "Lead-Free"



Tape & Reel Information



SECTION Y-Y

Ao	10.50	+/-	0.1
Bo	15.80	+/-	0.1
B2	10.25	+/-	0.1
Ko	4.90	+/-	0.1
F	11.50	+/-	0.1
P ₁	16.00	+/-	0.1
W	24.00	+/-	0.3

NOTES:

- 1.0 1.0 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ± 0.02
2.0 CAMBER NOT TO EXCEED 1mm in 100mm
3.0 MATERIAL: CONDUCTIVE BLACK STYRENIC ALLOY
4.0 K_0 MEASURED FROM A PLANE ON THE INSIDE BOTTOM OF THE POCKET TO THE TOP SURFACE OF THE CARRIER
5.0 MEASURED FROM CENTRELINE OF SPROCKET HOLE TO CENTRELINE OF POCKET
6.0 VENDOR: (OPTIONAL)
7.0 MUST ALSO MEET REQUIREMENTS OF EIA STANDAR #EIA-481A TAPING OF SURFACE MOUNT COMPONENTS FOR AUTOMATIC PLACEMENT
8.0 SURFACE RESISTIVITY OF MOLDED MATH MUST MEASURE LESS OR EQUAL TO 10^6 OHMS PER SQUARE. MEASURED IN ACCORDANCE TO PROCEDURE GIVEN IN ASTM D-257 & ASTM D-991
9.0 TOTAL LENGTH PER REEL MUST BE 45 METERS
10.0 © CRITICAL

Dimensions in millimeters and (inches)

Ordering Information Table

Device Code							
	32	C	T	Q	030	S	TRL PbF
	1	2	3	4	5	6	7 8
1	-	Current Rating (30A)					
2	-	Circuit Configuration					
		C = Common Cathode					
3	-	T = TO-220					
4	-	Schottky "Q" Series					
5	-	Voltage Rating (030 = 30V)					
6	-	- S = D²Pak -1= TO-262					
7	-	- none = Tube (50 pieces) - TRL = Tape & Reel (Left Oriented - for D²Pak only) - TRR = Tape & Reel (Right Oriented - for D²Pak only)					
8	-	- none = Standard Production - PbF = Lead-Free					

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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